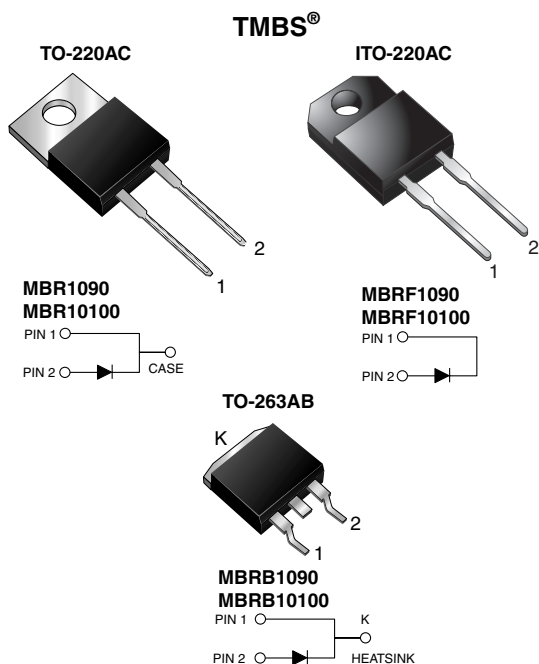




## High-Voltage Schottky Rectifier



### FEATURES

- Trench MOS Schottky technology
- Lower power losses, high efficiency
- Low forward voltage drop
- High forward surge capability
- High frequency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for TO-263AB package)
- Solder bath temperature 275 °C maximum, 10 s, per JESD 22-B106 (for TO-220AC and ITO-220AC package)
- Compliant to RoHS directive 2002/95/EC and in accordance to WEEE 2002/96/EC



**RoHS**  
COMPLIANT

### TYPICAL APPLICATIONS

For use in high frequency rectifier of switching mode power supplies, freewheeling diodes, dc-to-dc converters or polarity protection application.

### MECHANICAL DATA

**Case:** TO-220AC, ITO-220AC, TO-263AB

Molding compound meets UL 94 V-0 flammability rating

Base P/N-E3 - RoHS compliant, commercial grade

**Terminals:** Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test

**Polarity:** As marked

**Mounting Torque:** 10 in-lbs maximum

### PRIMARY CHARACTERISTICS

$I_{F(AV)}$	10 A
$V_{RRM}$	90 V, 100 V
$I_{FSM}$	150 A
$V_F$	0.65 V
$T_J \text{ max.}$	150 °C

### MAXIMUM RATINGS ( $T_C = 25\text{ °C}$ unless otherwise noted)

PARAMETER	SYMBOL	MBR1090	MBR10100	UNIT
Maximum repetitive peak reverse voltage	$V_{RRM}$	90	100	V
Working peak reverse voltage	$V_{RWM}$	90	100	V
Maximum DC blocking voltage	$V_{DC}$	90	100	V
Maximum average forward rectified current at $T_C = 133\text{ °C}$	$I_{F(AV)}$	10		A
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	$I_{FSM}$	150		A
Non-repetitive avalanche energy at $T_J = 25\text{ °C}$ , $L = 60\text{ mH}$	$E_{AS}$	130		mJ
Peak repetitive reverse current at $t_p = 2\text{ }\mu\text{s}$ , 1 kHz, $T_J = 38\text{ °C} \pm 2\text{ °C}$	$I_{RRM}$	0.5		A
Voltage rate of change (rated $V_R$ )	$dV/dt$	10 000		V/ $\mu\text{s}$
Isolation voltage (ITO-220AC only) From terminal to heatsink $t = 1\text{ min}$	$V_{AC}$	1500		V
Operating junction and storage temperature range	$T_J, T_{STG}$	- 65 to + 150		°C

# MBR(F,B)1090 & MBR(F,B)10100



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ELECTRICAL CHARACTERISTICS (T <sub>C</sub> = 25 °C unless otherwise noted)					
PARAMETER	TEST CONDITIONS		SYMBOL	VALUE	UNIT
Maximum instantaneous forward voltage <sup>(1)</sup>	I <sub>F</sub> = 10 A	T <sub>C</sub> = 25 °C	V <sub>F</sub>	0.80	V
	I <sub>F</sub> = 10 A	T <sub>C</sub> = 125 °C		0.65	
	I <sub>F</sub> = 20 A	T <sub>C</sub> = 125 °C		0.75	
Maximum reverse current at working peak reverse voltage <sup>(2)</sup>			I <sub>R</sub>	100	μA
				6.0	mA

**Notes**

(1) Pulse test: 300 μs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width ≤ 40 ms

THERMAL CHARACTERISTICS (T <sub>C</sub> = 25 °C unless otherwise noted)					
PARAMETER	SYMBOL	MBR	MBRF	MBRB	UNIT
Typical thermal resistance	R <sub>θJA</sub>	60	-	60	°C/W
	R <sub>θJC</sub>	2.0	3.5	2.0	

ORDERING INFORMATION (Example)					
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE
TO-220AC	MBR10100-E3/4W	1.845	4W	50/tube	Tube
ITO-220AC	MBRF10100-E3/4W	1.661	4W	50/tube	Tube
TO-263AB	MBRB10100-E3/4W	1.384	4W	50/tube	Tube
TO-263AB	MBRB10100-E3/8W	1.384	8W	800/reel	Tape and reel

## RATINGS AND CHARACTERISTICS CURVES

(T<sub>A</sub> = 25 °C unless otherwise noted)

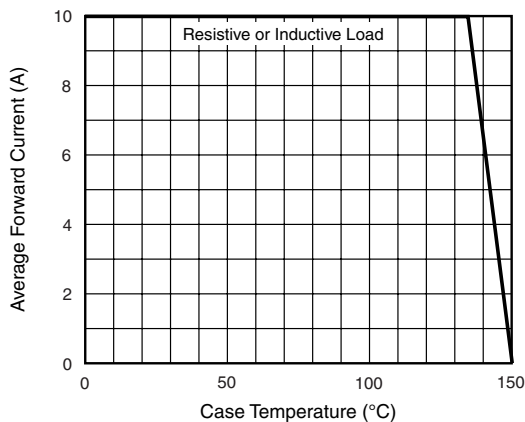


Figure 1. Forward Current Derating Curve

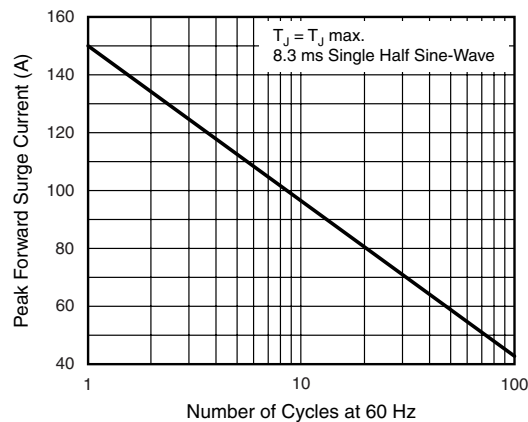


Figure 2. Maximum Non-Repetitive Peak Forward Surge Current



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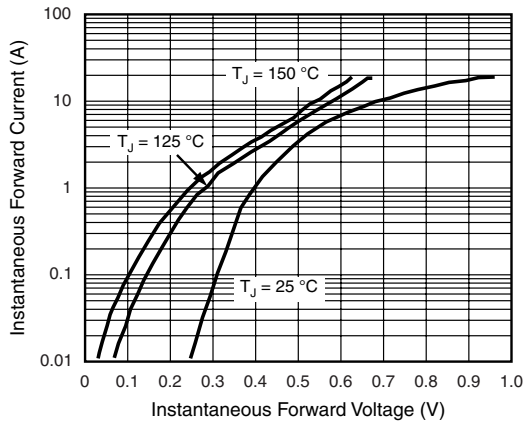


Figure 3. Typical Instantaneous Forward Characteristics

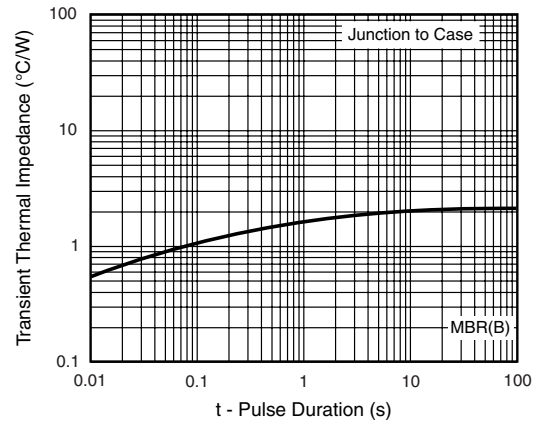


Figure 6. Typical Transient Thermal Impedance

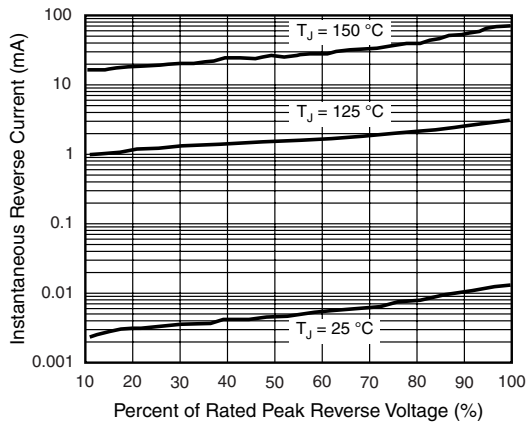


Figure 4. Typical Reverse Characteristics

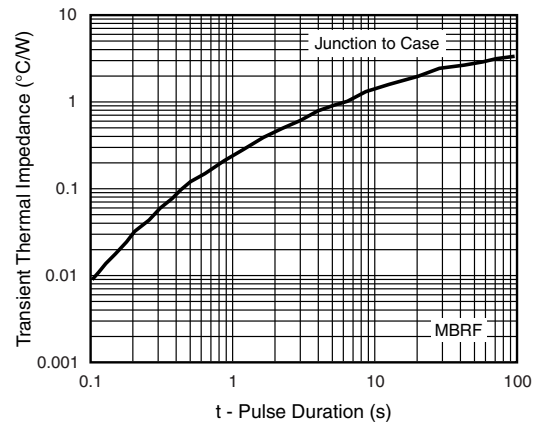


Figure 7. Typical Transient Thermal Impedance

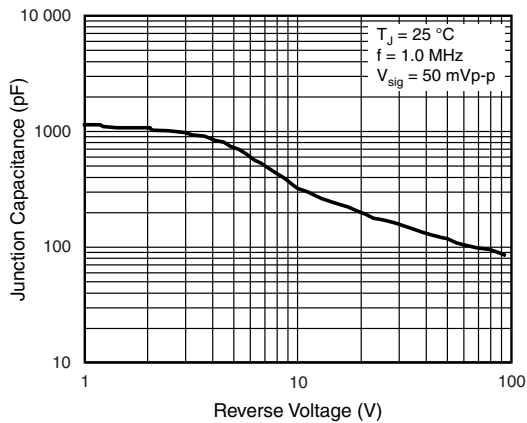


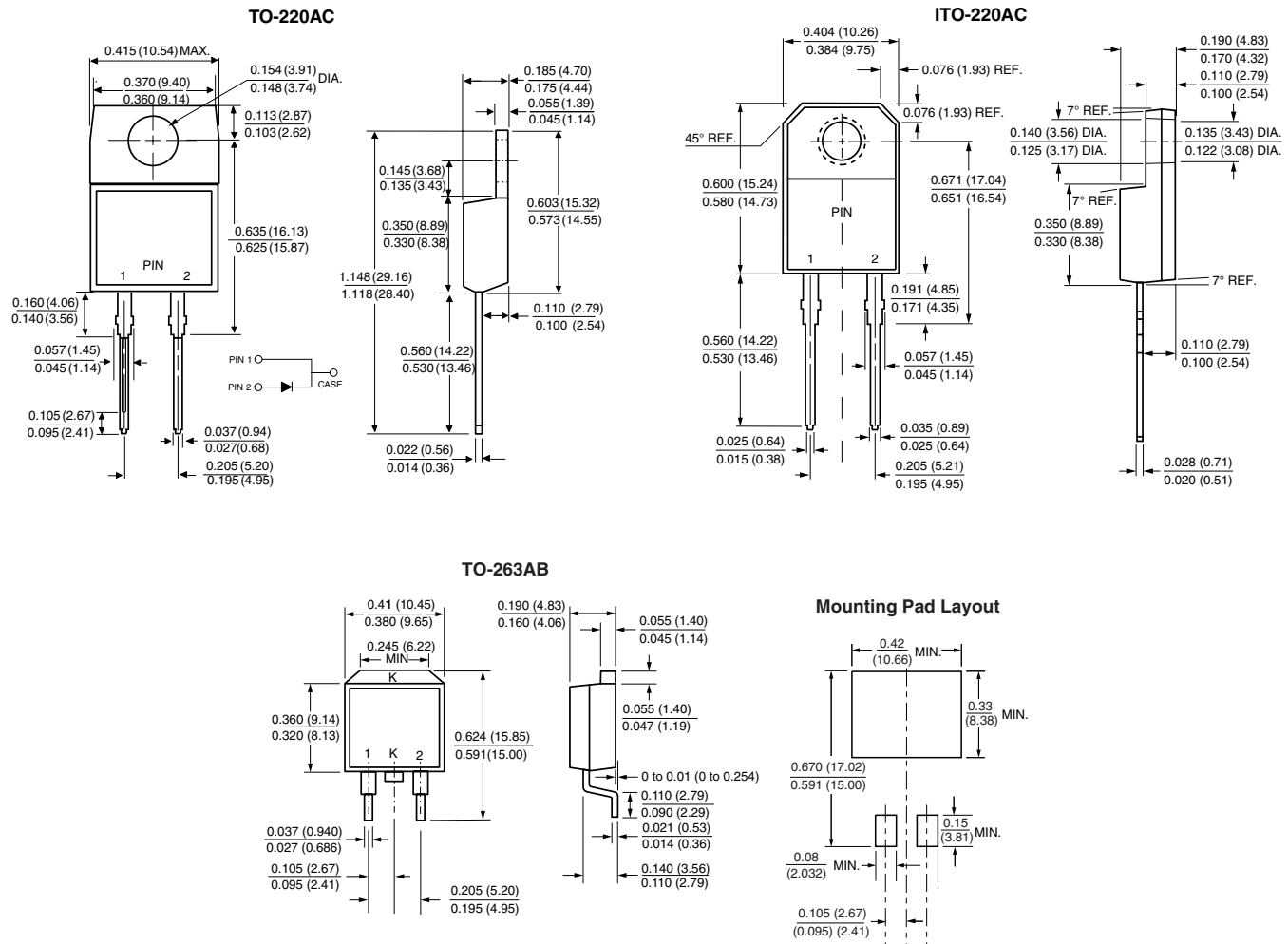
Figure 5. Typical Junction Capacitance

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## PACKAGE OUTLINE DIMENSIONS in inches (millimeters)





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